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# SiO2-Si film-substrate reflection polarizers for different mercury spectral lines

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## SiO<sub>2</sub>–Si film–substrate reflection polarizers for different mercury spectral lines

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In this Letter, we present data on  $SiO_2$ -Si film-substrate reflection polarizers designed to operate at different mercury spectral lines. We carried out the design at different wave-



Fig. 1. The least polarizing film thickness d for SiO<sub>2</sub>-Si p-( $\odot$ ) and s-( $\Delta$ ) suppressing reflection polarizers as functions of the wavelength  $\lambda$ .  $\lambda$  and d are in angstroms.



Fig. 2. The polarizing angle of incidence  $\phi$  for SiO<sub>2</sub>-Si p-( $\odot$ ) and s-( $\Delta$ ) suppressing reflection polarizers as functions of the wavelength  $\lambda$ .  $\phi$  is in degrees, and  $\lambda$  is in angstroms.





lengths for the SiO<sub>2</sub>–Si system. The procedure explained in Ref. 1 was used with  $\rho = 0$  (for *p*-suppressing polarizers) and  $\rho = \infty$  (for *s*-suppressing polarizers). The chosen wavelengths are the spectral lines of mercury:  $\lambda = 2537$  Å, 3131 Å, 3341 Å, 3650 Å, 4046 Å, 4358 Å, and 5461 Å; and the He–Ne laser light of  $\lambda = 6328$  Å. The optical properties of SiO<sub>2</sub> and Si are 1.50, 1.487, 1.48, 1.475, 1.47, 1.46, 1.45, and 1.46; (1.67, -j3.59), (4.90, -j3.63), (5.06, -j3.04), (6.63, -j2.74), (5.63, -j0.29), (4.83, -j0.116), (4.07, -j0.033), and (3.85, -j0.02), respectively.

The results are shown graphically in Figs.  $1-3.^2$  Figure 1 shows the dependence of the least polarizing film thickness on the wavelength for *p*- and *s*-suppressing polarizers. It is clear that the least polarizing film thickness increases monotonically with the wavelength for both kinds of polarizers. The polarizing angle for both kinds of polarizers does not show a similar monotonic behavior with the wavelength (Fig. 2). Figure 3 shows the unextinguished reflectance as a function of wavelength for the two kinds of polarizers. It is clear that better polarizers (with higher values of the unextinguished reflectance component) are obtainable at smaller wavelengths, where the extinction coefficient is larger.

A look at the  $\phi - \lambda$  curve, Fig. 2, shows that the difference ( $\phi_p - \phi_s$ ) decreases with the wavelength in certain regions of  $\lambda$ , so we expect the difference to approach zero by the appropriate choice of materials. By adding the appropriate mul-

Starting in September 1977 Camden County College will offer courses in a Laser-Electrooptic Technology program, one of the newest technologies in the nation. The Laser-Electrooptic Technology program prepares students to work in industry as technicians who test, maintain, and investigate operating lasers systems. Course work includes lectures and laboratories to teach and demonstrate the scientific and engineering principles of laser and electrooptic technology. Laboratories are an important part of the curriculum and emphasize trouble-shooting practical systems to improve the systems performance. tiple of the film-thickness period  $D_{\phi_{p,s}}^{1}$  to the least polarizing film thickness  $d_{p,s}$ , we obtain a film thickness at which the film-substrate system acts as a reflection *p*-suppressing polarizer at  $\phi_p$  and as a reflection *s*-suppressing polarizer at  $\phi_s$ . It is interesting to note that the condition  $\phi_p - \phi_s = 0^+$  leads to a nonreflecting film-substrate system.

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- 'Fables of exact design parameters are available from the authors.

### Polarization flipper for infrared laser beams: comment

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In a recent Letter,<sup>1</sup> Chraplyvy described a system of five mirrors capable of flipping the plane of polarization of laser beams by 90°. The purpose of this Letter is to point out that a similar property is possessed by the prism described by Klein<sup>2</sup> for use in X-Y scanning systems. This was brought to my attention by Treacy,<sup>3</sup> who also commented on the use of this property in the construction of a four-pass amplifier.<sup>4</sup> The system described in Ref. 2 employs two mirrors and a prism with three internally reflecting faces, while that in Ref. employs a prism with four internally reflecting faces. Chraplyvy<sup>5</sup> comments on the disadvantages of prisms in the far ir, owing to transparency limitations of materials and reflection losses at entrance and exit faces. However, these problems are avoided by using mirrors, instead of prisms, arranged in the same orientations as the prism faces. What we then have are several alternative mirror systems for use as polarization flippers, the choice between them being governed by ease of construction and convenience of adjustment.

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